

**FTA1274** TRANSISTOR (PNP)

**FEATURES**

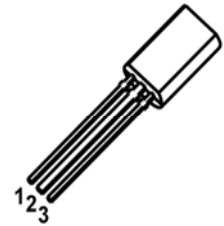
- Complementary to FTC3227
- General Purpose Applications

**MAXIMUM RATINGS (T<sub>a</sub>=25°C unless otherwise noted)**

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	-80	V
V <sub>CEO</sub>	Collector-Emitter Voltage	-80	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V
I <sub>C</sub>	Collector Current	-0.4	A
P <sub>C</sub>	Collector Power Dissipation	1	W
R <sub>θJA</sub>	Thermal Resistance From Junction To Ambient	125	°C/W
T <sub>j</sub>	Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature	-55~+150	°C

**TO – 92L**

1. EMITTER
2. COLLECTOR
3. BASE



**ELECTRICAL CHARACTERISTICS (T<sub>a</sub>=25°C unless otherwise specified)**

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> = -1mA, I <sub>E</sub> =0	-80			V
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> =-5mA, I <sub>B</sub> =0	-80			V
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =-1mA, I <sub>C</sub> =0	-5			V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> =-50V, I <sub>E</sub> =0			-0.1	μA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> =-5V, I <sub>C</sub> =0			-0.1	μA
DC current gain	h <sub>FE(1)</sub>	V <sub>CE</sub> =-2V, I <sub>C</sub> =-50mA	70		240	
	h <sub>FE(2)</sub>	V <sub>CE</sub> =-2V, I <sub>C</sub> =-200mA	40			
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =-200mA, I <sub>B</sub> =-20mA			-0.4	V
Base-emitter voltage	V <sub>BE</sub>	V <sub>CE</sub> =-2V, I <sub>C</sub> =-5mA	-0.55		-0.8	V
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> =-10V, I <sub>E</sub> =0, f=1MHz		14		pF
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> =-10V, I <sub>C</sub> =-10mA		100		MHz

**CLASSIFICATION OF h<sub>FE(1)</sub>**

RANK	O	Y
RANGE	70-140	120-240